

# N-Channel Enhancement-Mode Vertical DMOS FETs

#### Ordering Information

BV <sub>DSS</sub> /	R <sub>DS(ON)</sub> (max)	I <sub>D(ON)</sub>	Order Number / Package		
BV <sub>DGS</sub>		(min)	TO-92	20-Pin C-Dip	
220V	1.25Ω	5.0A	—	VN2222NC	
240V	1.25Ω	5.0A	VN2224N3	—	

#### **High Reliability Devices**

See pages 5-4 and 5-5 for MILITARY STANDARD Process Flows and Ordering Information.

#### **Features**

- Free from secondary breakdown
- Low power drive requirement
- Ease of paralleling
- □ Low C<sub>ISS</sub> and fast switching speeds
- Excellent thermal stability
- Integral Source-Drain diode
- High input impedance and high gain

# **Applications**

- Motor controls
- Converters
- Amplifiers
- Switches
- Power supply circuits
- Drivers (relays, hammers, solenoids, lamps, memories, displays, bipolar transistors, etc.)

### **Absolute Maximum Ratings**

BV <sub>DGS</sub>
= · DG3
± 20V
o +150°C
300°C

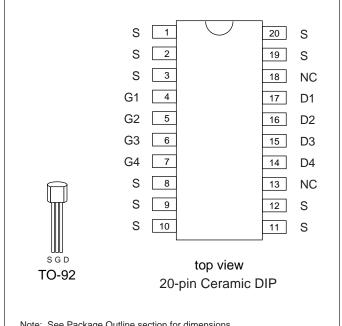
\* Distance of 1.6 mm from case for 10 seconds.

# Advanced DMOS Technology

These enhancement-mode (normally-off) transistors utilize a vertical DMOS structure and Supertex's well-proven silicon-gate manufacturing process. This combination produces devices with the power handling capabilities of bipolar transistors and with the high input impedance and positive temperature coefficient inherent in MOS devices. Characteristic of all MOS structures, these devices are free from thermal runaway and thermally-induced secondary breakdown.

Supertex's vertical DMOS FETs are ideally suited to a wide range of switching and amplifying applications where high breakdown voltage, high input impedance, low input capacitance, and fast switching speeds are desired.

# Package Options



Note: See Package Outline section for dimensions.

11/12/01

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# **Thermal Characteristics**

Package	I <sub>D</sub> (continuous)*	I <sub>D</sub> (pulsed)	Power Dissipation @ T <sub>C</sub> = 25°C	$^{ heta_{jc}}$ °C/W	θ <sub>ja</sub> °C/W	I <sub>DR</sub> *	I <sub>DRM</sub>
TO-92	540mA	5.0A	1.0W	125	170	540mA	5.0A

\*  $I_{_{D}}$  (continuous) is limited by max rated  $T_{_{j}}$ 

#### Electrical Characteristics (@ 25°C unless otherwise specified)

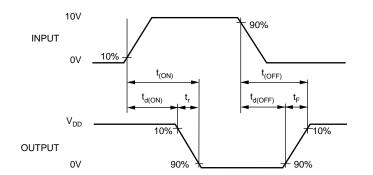
Symbol	Parameter		Min	Тур	Max	Unit	Conditions	
$BV_{DSS}$	Drain-to-Source	VN2224	240			V	$V_{GS} = 0V, I_D = 5mA$	
	Breakdown Voltage	VN2222	220					
V <sub>GS(th)</sub>	Gate Threshold Voltage		1.0		3.0	V	$V_{GS} = V_{DS}, I_D = 5mA$	
$\Delta V_{GS(th)}$	Change in $V_{GS(th)}$ with Temperature			-4	-5	mV/°C	$V_{GS} = V_{DS}, I_D = 5mA$	
I <sub>GSS</sub>	Gate Body Leakage			1	100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
I <sub>DSS</sub>	I <sub>DSS</sub> Zero Gate Voltage Drain Current				50	μΑ	$V_{GS} = 0V, V_{DS} = Max Rating$	
					5	mA	$V_{GS} = 0V, V_{DS} = 0.8$ Max Rating $T_A = 125^{\circ}C$	
I <sub>D(ON)</sub>	ON-State Drain Current		2			А	$V_{GS} = 5V, V_{DS} = 25V$	
				10			$V_{GS} = 10V, V_{DS} = 25V$	
-D3(UN)	Static Drain-to-Source			1.0	1.5	Ω	$V_{GS} = 5V, I_D = 2A$	
	ON-State Resistance			0.9	1.25		$V_{GS} = 10V, I_D = 2A$	
$\Delta R_{DS(ON)}$	Change in R <sub>DS(ON)</sub> with Temperature			1.0	1.4	%/°C	$V_{GS} = 10V, I_{D} = 2A$	
G <sub>FS</sub>	Forward Transconductance		1.0	2.2		Ω	$V_{DS} = 25V, I_{D} = 2A$	
C <sub>ISS</sub>	Input Capacitance Common Source Output Capacitance			300	350	pF	V <sub>GS</sub> = 0V, V <sub>DS</sub> = 25V f = 1 MHz	
C <sub>OSS</sub>				85	150			
C <sub>RSS</sub>	Reverse Transfer Capacitance			20	35			
t <sub>d(ON)</sub>	Turn-ON Delay Time			6	15			
t <sub>r</sub>	Rise Time   Turn-OFF Delay Time			16	25	ns	$V_{DD} = 25V$ $I_D = 2A$ $R_{GEN} = 10\Omega$	
t <sub>d(OFF)</sub>				65	90			
t <sub>f</sub>	Fall Time			30	60			
$V_{SD}$	Diode Forward Voltage Drop			0.8	1.0	V	$V_{GS} = 0V, I_{SD} = 100mA$	
t <sub>rr</sub>	Reverse Recovery Time			500		ns	$V_{GS} = 0V, I_{SD} = 1A$	

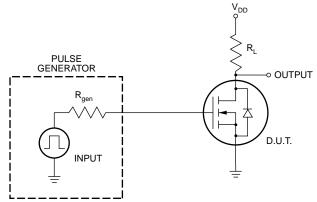
Notes:

1. All D.C. parameters 100% tested at 25°C unless otherwise stated. (Pulse test: 300µs pulse, 2% duty cycle.)

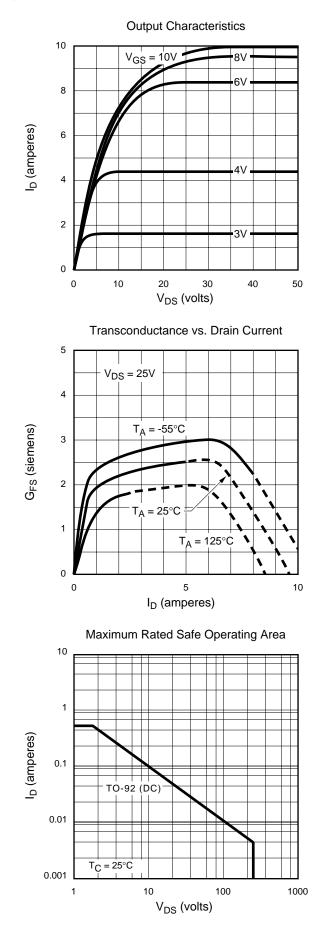
2. All A.C. parameters sample tested.

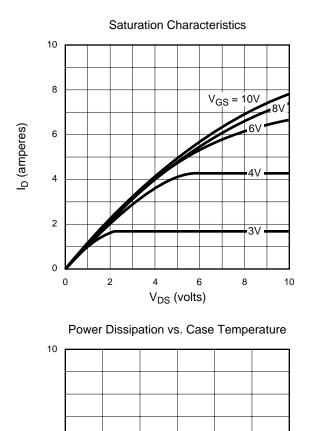
# Switching Waveforms and Test Circuit

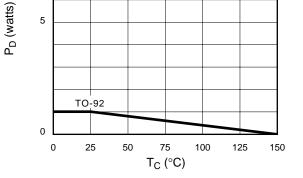




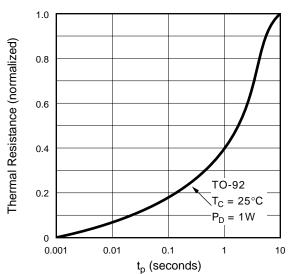
#### **Typical Performance Curves**



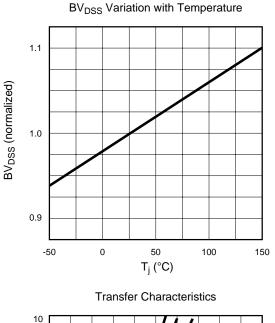


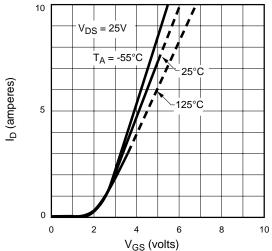


**Thermal Response Characteristics** 

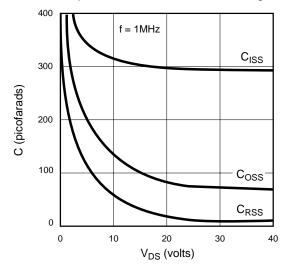


### **Typical Performance Curves**

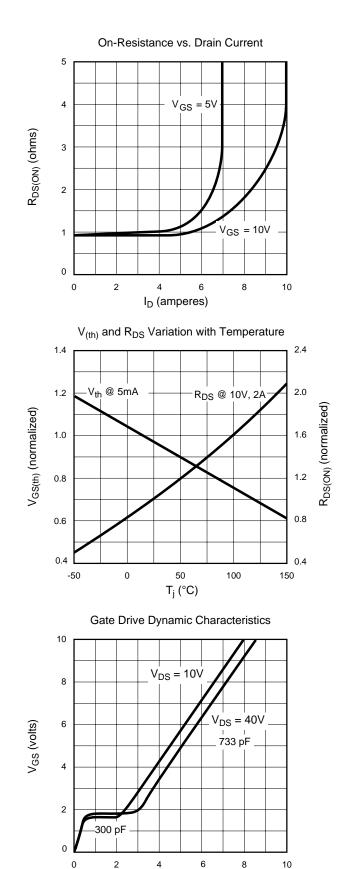




Capacitance vs. Drain-to-Source Voltage







Q<sub>G</sub> (nanocoulombs) 11/12/01

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